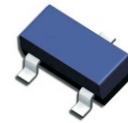


## BC846AW-G Thru. BC848CW-G (NPN)

RoHS Device



### Features

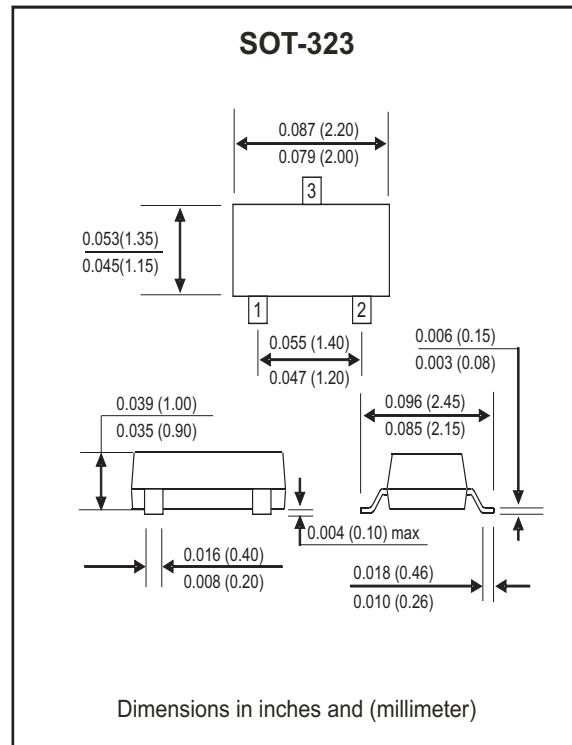
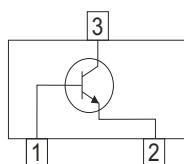
- Power dissipation  
PCM: 0.15W (@TA=25 °C)
- Collector current  
ICM: 0.1A
- Collector-base voltage  
VCBO: BC846W=80V  
BC847W=50V  
BC848W=30V
- Operating and storage junction temperature range: TJ, TSTG= -55 to +150 °C

### Mechanical data

- Case: SOT-323, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Approx. weight: 0.008 grams

### Circuit diagram

- 1.BASE
- 2.EMITTER
- 3.COLLECTOR



### Maximum Ratings (at Ta=25 °C unless otherwise noted)

Parameter	Symbol	Value	Units
Collector-Base Voltage	VCBO	80 50 30	V
Collector-Emitter Voltage	VCEO	65 45 30	V
Emitter-Base Voltage	VEBO	6 5	V
Collector Current -Continuous	Ic	0.1	A
Collector Power Dissipation	Pc	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature Range	TSTG	-55 to +150	°C

# Small Signal Transistor

## Electrical Characteristics

(BC846AW-G Thru. BC848CW-G, @ $T_A = 25^\circ C$  unless otherwise specified)

Parameter		Symbol	Test Conditions	MIN	TYP	MAX	Units
Collector-Base Breakdown Voltage	BC846W-G	V <sub>CBO</sub>	$I_C = 10\mu A, I_E = 0$	80			V
	BC847W-G			50			
	BC848W-G			30			
Collector-Emitter Breakdown Voltage	BC846W-G	V <sub>CEO</sub>	$I_C = 10mA, I_B = 0$	65			V
	BC846W-G			45			
	BC848W-G			30			
Emitter-Base Break Voltage	BC846W-G, BC847W-G BC848W-G	V <sub>EBO</sub>	$I_E = 10\mu A, I_C = 0$	6			V
Collector Cutoff Current		I <sub>CBO</sub>	V <sub>CB</sub> =30V	5		15	
DC Current Gain	BC846AW,847AW,848AW	h <sub>FE</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10 $\mu A$		90		
	BC846BW,847BW,848BW				150		
	BC847CW,848CW		V <sub>CE</sub> = 5V, I <sub>C</sub> = 2mA	270			
	BC846AW,847AW,848AW			110		220	
	BC846BW,847BW,848BW			200		450	
	BC847CW,848CW			420		800	
Collector-Emitter Saturation Voltage		V <sub>CES(sat)</sub>	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0.5mA I <sub>C</sub> = 100mA, I <sub>B</sub> = 0.5mA			0.25 0.60	V
Base-Emitter Saturation Voltage		V <sub>BE(sat)</sub>	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0.5mA I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA		0.7 0.9		V
Base-Emitter Voltage		V <sub>BE(on)</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 2mA V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA	580	660	700 770	mV
Transition Frequency		f <sub>T</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA f = 100MHz	100			MHz
Collector Output Capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10V, f = 1MHz			4.5	pF
Noise Figure	BC846AW,847AW,848AW BC846BW,847BW,848BW BC847CW,848CW	NF	V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.2mA f = 1KHz, R <sub>s</sub> = 2KΩ BW = 200Hz			10 4	dB

# Small Signal Transistor

Electrical Characteristic Curves (BC846AW-G Thru. BC848CW-G)

Fig.1 Normalized DC Current Gain

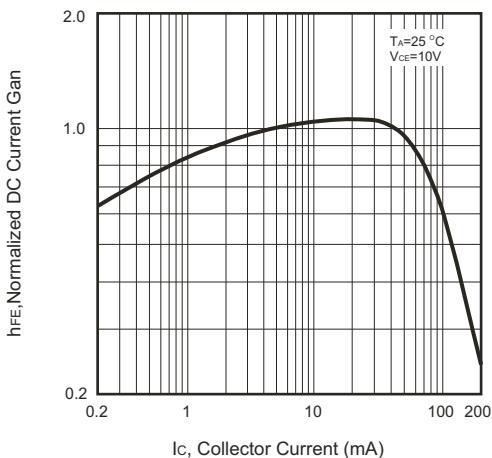


Fig.2 Saturation and On voltage

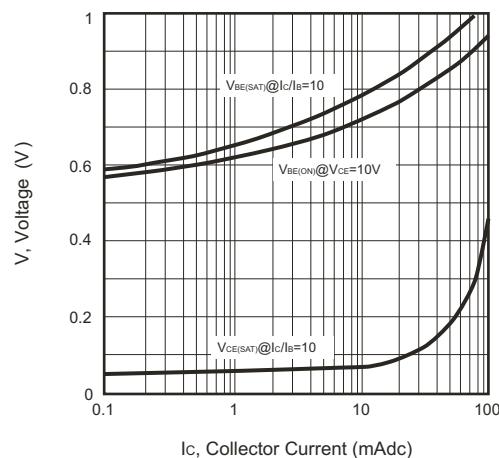


Fig.3 Collector Saturation Region

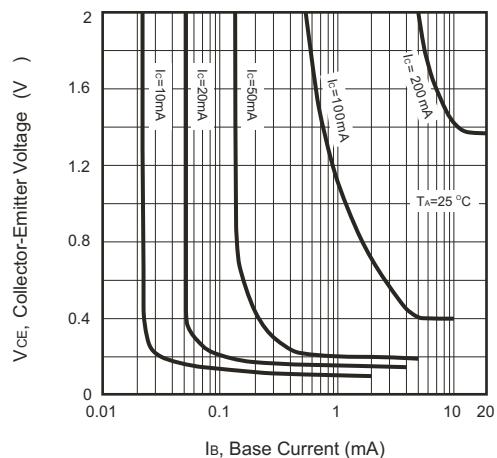


Fig.4 Base-Emitter Temperature Coefficient

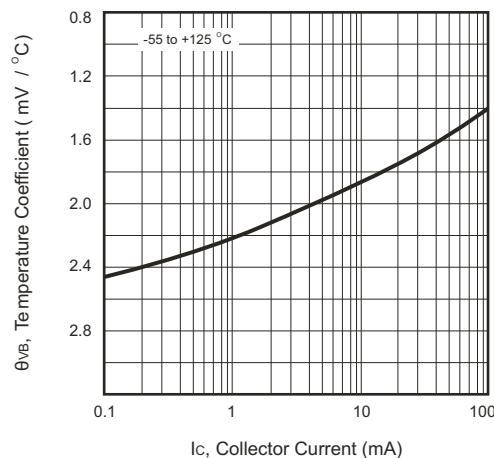


Fig.5 Capacitance

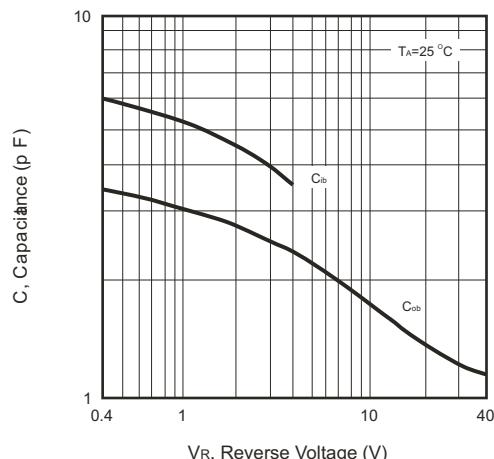
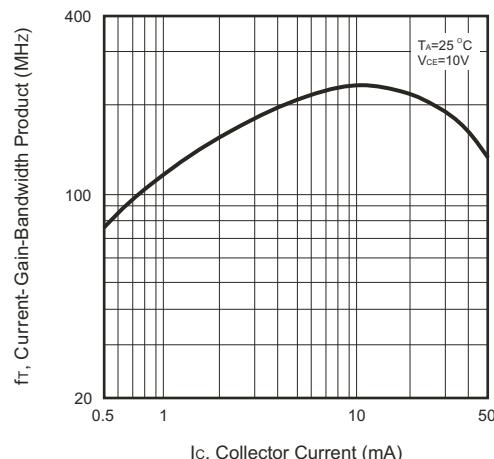
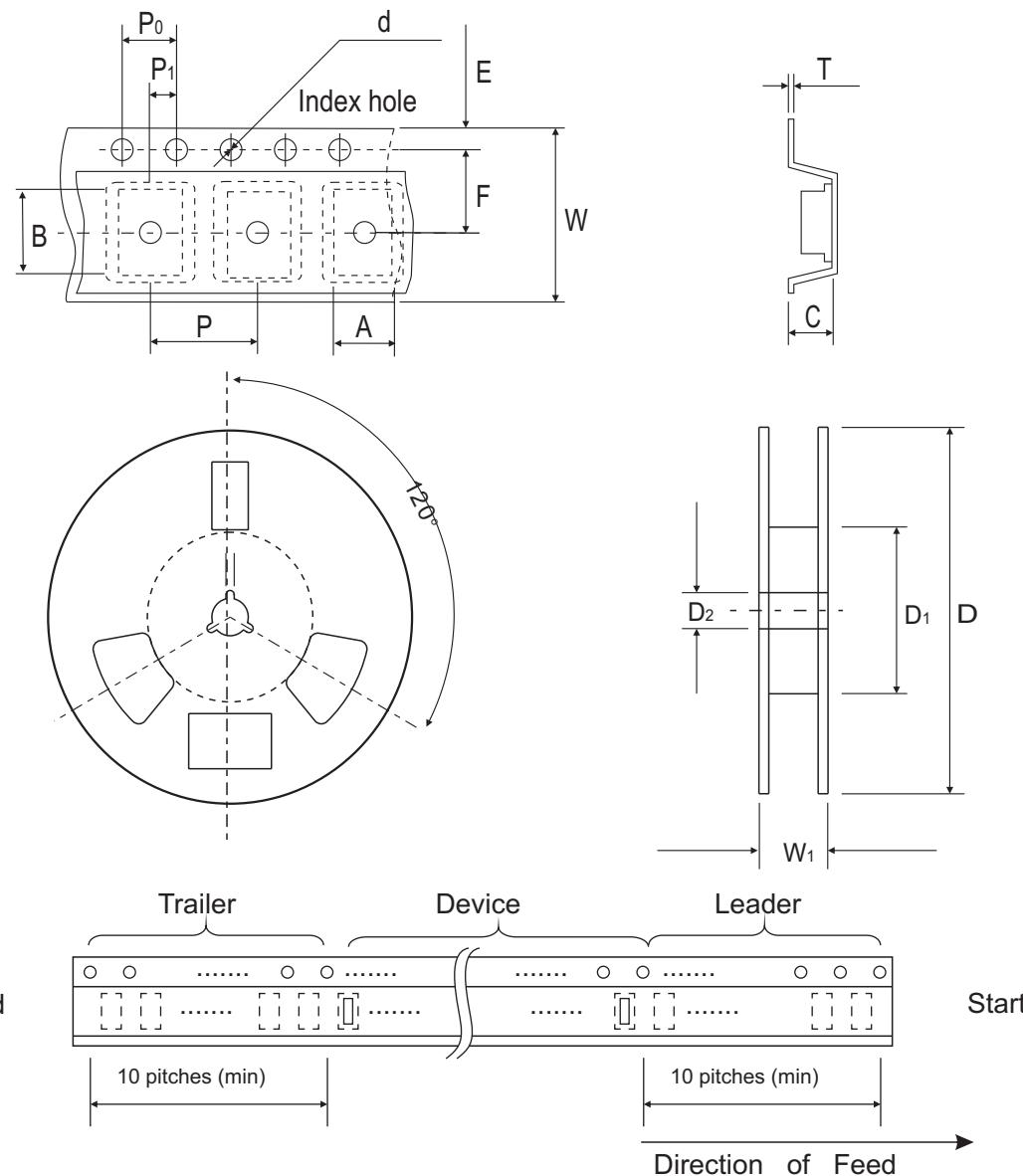


Fig.6 Current Gain Bandwidth Product



## Reel Taping Specification

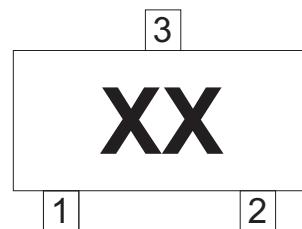


SOT-323	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	$2.25 \pm 0.10$	$2.55 \pm 0.10$	$1.19 \pm 0.10$	$1.55 \pm 0.10$	$178 \pm 1.00$	$54.40 \pm 0.40$	$13.0 \pm 0.20$
	(inch)	$0.089 \pm 0.004$	$0.100 \pm 0.004$	$0.047 \pm 0.004$	$0.061 \pm 0.004$	$7.008 \pm 0.039$	$2.142 \pm 0.016$	$0.512 \pm 0.008$

SOT-323	SYMBOL	E	F	P	P0	P1	W	W1
	(mm)	$1.75 \pm 0.10$	$3.50 \pm 0.05$	$4.00 \pm 0.10$	$4.00 \pm 0.10$	$2.00 \pm 0.10$	$8.00 \pm 0.30 / -0.10$	$9.50 \pm 1.00$
	(inch)	$0.069 \pm 0.004$	$0.138 \pm 0.002$	$0.158 \pm 0.004$	$0.158 \pm 0.004$	$0.079 \pm 0.004$	$0.315 \pm 0.012 / -0.004$	$0.374 \pm 0.039$

## Marking Code

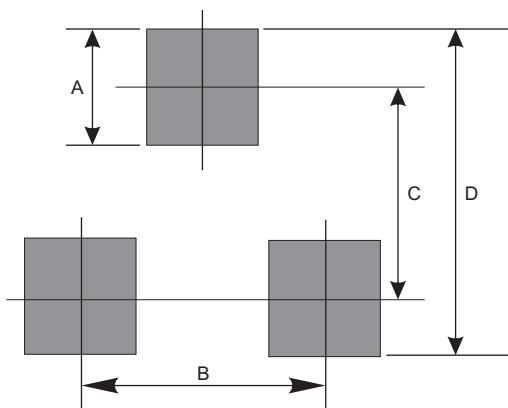
Part Number	Marking Code
BC846AW-G	1A
BC847AW-G	1E
BC848AW-G	1J
BC846BW-G	1B
BC847BW-G	1F
BC848BW-G	1K
BC847CW-G	1G
BC848CW-G	1L



**xx = Product type marking code**

## Suggested PAD Layout

SIZE	SOT-323	
	(mm)	(inch)
A	0.80	0.031
B	1.30	0.051
C	1.94	0.076
D	2.74	0.108



## Standard Package

Case Type	Qty per Reel	Reel Size
	(Pcs)	(inch)
SOT-323	3000	7

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